Universal AC Input, 12 V Output, 10 W E-meter Power Supply



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DESIGN NOTE

Device	Application	Input Voltage	Output Power	Topology	I/O Isolation	
NCP1075, NCP431	Smart Meters, Electric Meters, White Goods	85 to 300 Vac	5 to 10 W	Flyback	Isolated (3 kV)	
Characteristic			Output Specification			
	Output Voltage		12 Vdc			
Ripple			150 mV p/p @ Full Load			
Nominal Current			800 mA			
Max Current			1.0 A Maximum			
Min Current			Zero			
	PFC (Yes/No)		No, (Pout < 25 W)			
	Efficiency		77% per Energy Star			
	Inrush Limiting/Fuse		Inrush Resistor (R1) & Fuse			
	Operating Temp. Range)	0 to +50°C			
Cooling Method/Supply Orientation			Convection			
	Signal Level Control		None			

Table 1. DEVICE DETAILS

Circuit Description

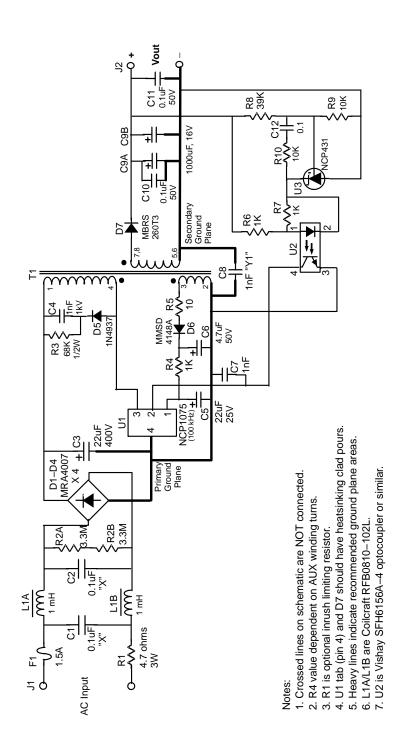
This design note describes a simple, low power (10 W or less), universal AC input, constant voltage power supply intended for powering utility electric meters or similar industrial equipment or white goods where isolation from the AC mains is required and low cost and high efficiency is essential.

The featured power supply is a simple flyback topology utilizing ON Semiconductor's new NCP1075 SOT-223 monolithic switcher. This Design Note provides the complete circuit schematic details and transformer design for a 12 V, 800 mA amp power supply. Other output voltages from 3.3 Vdc up to 28 Vdc are easy to implement by modifying the values (or ratings) of a few of the secondary side output components and the flyback transformer's secondary winding (T1). The simple input EMI filter is adequate to pass Level B for FCC conducted EMI compliance and the NCP431 plus optocoupler feedback scheme provides for excellent line and load regulation along with high input-to-output isolation. Performance characteristics for efficiency, output ripple, and internal MOSFET drain switching characteristics are shown in the figures and plots below. Enhanced input transient protection (lightning, etc.) can be accomplished with the addition of an appropriate TVS device across C2.

Key Features

- Universal AC Input Range (85–300 Vac).
- Input Filter (Pi-network) for Conducted EMI Attenuation and Input Transient Protection
- Very Low Standby (No Load) Power Consumption
- Frequency Foldback under Light Load and/or Over-current Conditions
- Secondary Circuit Easily Configured for Different Output Voltages
- Inherent Over-current, Over-voltage and Over-temperature Protection

CIRCUIT SCHEMATIC



10 W NCP1075 Power Supply with Universal AC Input

12 V Transformer Design

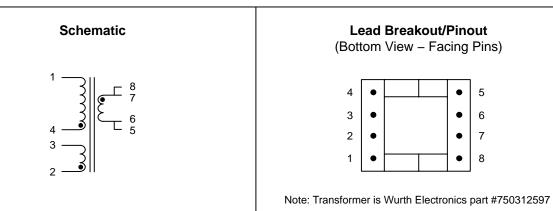
Project/Customer: ON Semiconductor – NCP1075 10W PSU Part Description: 10 W Flyback Transformer, 100 kHz, 12 V/0.8 A Out Schematic ID: T1 Core Type: EF16 (E16/8/5); 3C90 Material or Similar Core Gap: Gap for 1.7 to 2 mH Inductance across Primary (Pins 1 – 4) Inductance: 1.85 mH \pm 5% Bobbin Type: 8 Pin Horizontal Mount for EF16

Windings (in order):

Winding #/Type	Turns/Material/Gauge/Insulation Data				
Primary (4 – 1)	100 turns of #35HN over 2 layers evenly. Insulate with a layer of Mylar tape.				
12 V Secondary (7, 8 – 5, 6)	10 turns of #24 triple insulated wire over one layer. Self leads to pins per drawing. Insulate with a layer of Mylar tape.				
Vcc/Boost (3 – 2)	10 turns of #35HN spiral wound over 1 layer with 2 mm end margins. Insulate with tape for 3 kV.				

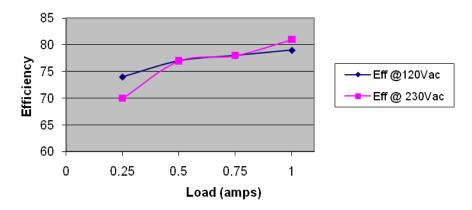
Varnish assembly

Hipot: 3 kV from Vcc/primary to secondary.

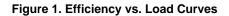


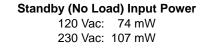
A 5 Vout version of this transformer is available on request.

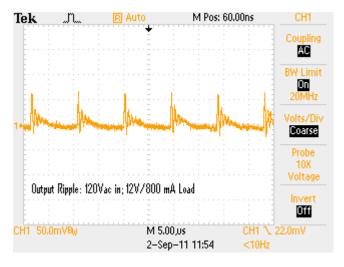
12 Vout Efficiency vs Load (NCP1075)



Average efficiency for both 120 Vac and 230 Vac was 77%.







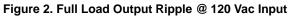




Figure 3. MOSFET Drain Voltage (120 Vac Input, 12 V, 1 A Load on Output)

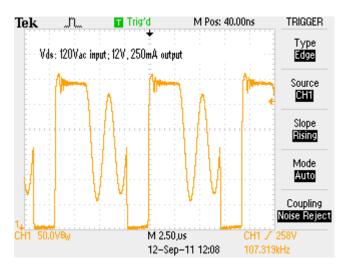


Figure 4. MOSFET Drain Voltage (120 Vac Input, 12 V, 250 mA Output)

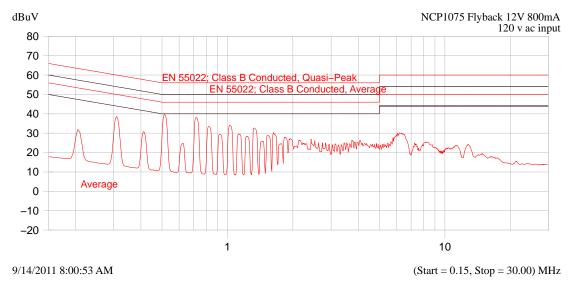


Figure 5. EMI Profile

BILL OF MATERIALS

Table 2. BILL OF MATERIALS FOR 12 Vout, 10 W NCP1075 FLYBACK

Designator	Qty	Description	Value	Tolerance	Footprint	Manufacturer	Manufacturer Part Number	Substitution Allowed
D7 (12 Vout)	1	Schottky Diode	2 A, 60 V		SMB	ON Semiconductor	MBRS260T3	No
D7 (5 Vout)	1	Schottky Diode	3 A, 40 V		SMB	ON Semiconductor	MBRS2040L	No
D1, D2, D3, D4	4	Diode – 60 Hz	1 A, 800 V		SMA	ON Semiconductor	MRA4007	No
D5	1	Diode – Fast Recov.	1 A, 600 V		Axial Lead	ON Semiconductor	1N4937	No
D6	1	Signal Diode	100 mA, 100 V		SOD-123	ON Semiconductor	MMSD4148A	No
U3	1	Programmable Zener	2.5 V		SOIC8/ SOT23	ON Semiconductor	NCP431A	No
U2	1	Optocoupler	CTR >/= 0.5		4-pin	Vishay or NEC	SFH6156A–4 or PS2561L–1	Yes
U1	1	Switcher IC – NCP1075	100 kHz		SOT223	ON Semiconductor	NCP1075ST100	No
C1, C2	2	"X" Cap, Box Type	100 nF, X2		LS = 15 mm	Rifa, Wima	TBD	Yes
C8	1	"Y1" Cap, Disc Type	1 nF, Y1		LS = 7.5 mm	Rifa, Wima	TBD	Yes
C4	1	Ceramic Cap, Disc	1 nF, 1 kV	5%	LS = 7.5 mm	Rifa, Wima	TBD	Yes
C7	1	Ceramic Cap, Monolythic	1 nF, 50 V	10%	1206	AVX, Murata	TBD	Yes
C10, C11, C12	3	Ceramic Cap, Monolythic	100 nF, 50 V	10%	1206	AVX, Murata	TBD	Yes
C3	1	Electrolytic Cap	22 μF, 400/450 V	10%	LS = 7.5 mm, D = 16 mm	UCC, Panasonic	TBD	Yes
C6	1	Electrolytic Cap	4.7 μF, 50 Vdc	10%	LS = 2.5 mm, D = 6.3 mm	UCC, Panasonic	TBD	Yes
C5	1	Electrolytic Cap	22 μF, 25 V	10%	LS = 2.5 mm, D = 6.3 mm	UCC, Panasonic	TBD	Yes
C9A, C9B	2	Electrolytic Cap	1000 μF, 16 V	10%	LS = 5 mm, D = 12.5 mm	UCC, Panasonic	TBD	Yes
R1	1	Resistor, 3 W, Wire Wound	4.7 Ω, 3 W	10%	LS = 7.5 mm, D = 7 mm	Ohmite, Dale	TBD	Yes
R3	1	Resistor, 0.5 W, Metal Film	68 kΩ, 0.5 W	10%	Axial Lead; LS = 12.5 mm	Ohmite, Dale	TBD	Yes
R2A, R2B	2	Resistor, 1/4 W SMD	3.3 MΩ	5%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R5	1	Resistor, 1/4 W SMD	10 Ω	5%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R4	1	Resistor, 1/4 W SMD	1 kΩ	5%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R9, R10	2	Resistor, 1/4 W SMD	10 kΩ	1%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R7	1	Resistor, 1/4 W SMD	1 kΩ	1%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R6 (12 Vout)	1	Resistor, 1/4 W SMD	1 kΩ	1%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R6 (5 Vout)	1	Resistor, 1/4 W SMD	240 Ω	1%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R8 (12 Vout)	1	Resistor, 1/4 W SMD	39 kΩ	5%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
R8 (5 Vout)	1	Resistor, 1/4 W SMD	10 kΩ	1%	SMD 1206	AVX, Vishay, Dale	TBD	Yes
F1	1	Fuse, TR–5 Style	1.5 A		TR-5, LS = 5 mm	Minifuse		Yes
L1A/B	2	Inductor (EMI Choke)	1 mH, 500 mA		See Wurth Drawing	LS = 5 mm, D = 8 mm	7447728102	Yes
T1 (12 Vout)	1	Transformer	E20/10/6 Core		See Mag Drawing	Wurth Magnetics		Yes
J1, J2	2	Screw Terminal			LS = 0.2"	DigiKey	# 281–1435–ND	Yes

NOTE: Grey indicates part change with Vout change.

REFERENCES

- [1] ON Semiconductor Data Sheet for <u>NCP1251/D</u> Controller in TSOP6 Package.
- [3] ON Semiconductor Application Note <u>AND8489/D</u>
- [2] ON Semiconductor Design Notes <u>DN05012/D</u>, <u>DN05014/D</u>, <u>DN05017/D</u>.

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